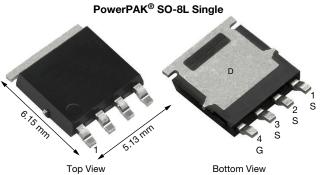
## SQJ476EP



**Vishay Siliconix** 

# Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V <sub>DS</sub> (V)	100
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.038
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.050
I <sub>D</sub> (A)	23
Configuration	Single
Package	PowerPAK SO-8L



### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified d
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



5 15 133 1 1 5 13 mm	G G	N-Cha	Innel MOSFET	
Top View ABSOLUTE MAXIMUM RATIN	Bottom View IGS ( $T_c = 25 ^{\circ}C$ unless	otherwise noted	)	
PARAMETER		SYMBOL	LIMIT	UNI
Drain-Source Voltage		V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	± 20	V	
Continuous Duoin Current	T <sub>C</sub> = 25 °C	Ι <sub>D</sub>	23	
Continuous Drain Current	T <sub>C</sub> = 125 °C		13	
Continuous Source Current (Diode Condu	iction) <sup>a</sup>	Is	30	А
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	45	
Single Pulse Avalanche Current		I <sub>AS</sub>	18	
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	16	mJ
Maximum Bawar Dissinction b	T <sub>C</sub> = 25 °C	D	45	W
Maximum Power Dissipation <sup>b</sup>	T <sub>C</sub> = 125 °C	P <sub>D</sub>	15	VV
Operating Junction and Storage Temperature Range Soldering Recommendations (Peak Temperature) <sup>e, f</sup>		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	**
			260	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount <sup>c</sup>	R <sub>thJA</sub>	70	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	3.3	0/10

#### Notes

- a. Package limited.
- b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.
- e. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static					•	•	
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub>	= 0, I <sub>D</sub> = 250 μA	100	-	-	v
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	= V <sub>GS</sub> , I <sub>D</sub> = 250 μΑ	1.5	2.0	2.5	v
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	$0 \text{ V}, \text{V}_{\text{GS}} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V	-	-	1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V, T <sub>J</sub> = 175 °C	-	-	150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	15	-	-	Α
		$V_{GS} = 10 V$	I <sub>D</sub> = 10 A	-	0.030	0.038	
Ducia Course On Ototo Decistores a	P	$V_{GS} = 4.5 V$	I <sub>D</sub> = 5 A	-	0.037	0.050	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 V$	I <sub>D</sub> = 10 A, T <sub>J</sub> = 125 °C	-	-	0.065	Ω
		$V_{GS} = 10 V$	I <sub>D</sub> = 10 A, T <sub>J</sub> = 175 °C	-	-	0.081	1
Forward Transconductance b	9 <sub>fs</sub>	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 10 A	-	22	-	S
Dynamic <sup>b</sup>							•
Input Capacitance	C <sub>iss</sub>			-	515	700	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 25 V, f = 1 MHz	-	275	400	pF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	24	40	
Total Gate Charge <sup>c</sup>	Qg			-	10	20	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	-	2	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	2	-	
Gate Resistance	Rg		f = 1 MHz	0.9	2.1	3.3	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	5	10	
Rise Time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub>	= 50 V, $R_{L}$ = 10 $\Omega$	-	20	35	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 5 A$ ,	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	11	20	ns
Fall Time <sup>c</sup>	t <sub>f</sub>	1		-	50	80	1
Source-Drain Diode Ratings and Chara	acteristics <sup>b</sup>						
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	45	Α
Forward Voltage	V <sub>SD</sub>	I.	= 10 A, V <sub>GS</sub> = 0	-	0.88	1.2	V

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

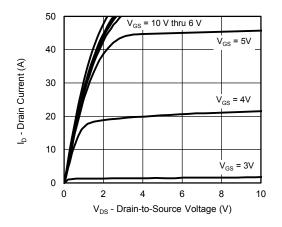
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

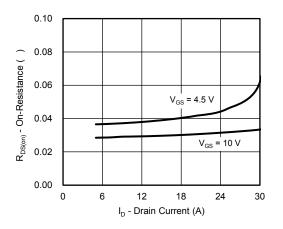
2



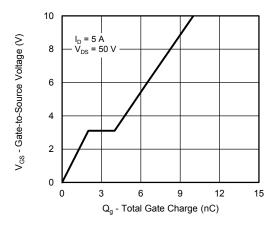
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



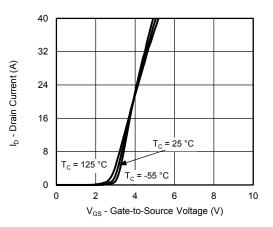
**Output Characteristics** 



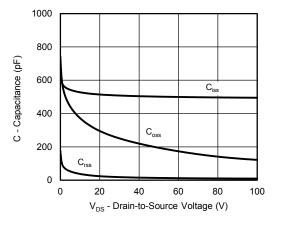
**On-Resistance vs. Drain Current** 



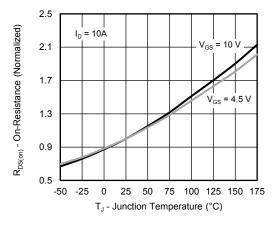
Gate Charge



**Transfer Characteristics** 



Capacitance



#### **On-Resistance vs. Junction Temperature**

S16-0424-Rev. A, 14-Mar-16

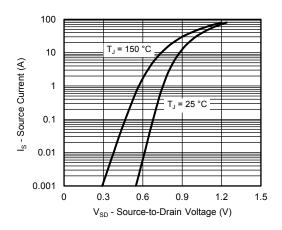
3

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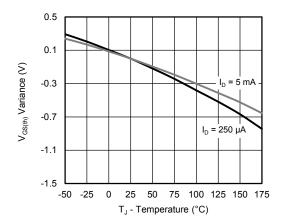
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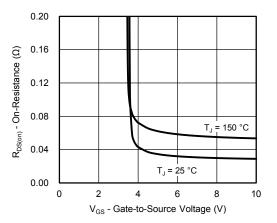
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



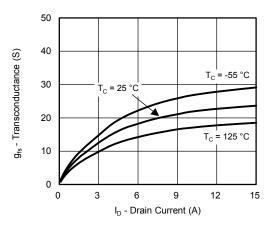
Source Drain Diode Forward Voltage



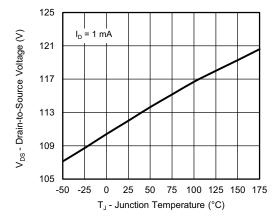
**Threshold Voltage** 



**On-Resistance vs. Gate-to Source Voltage** 



Transconductance



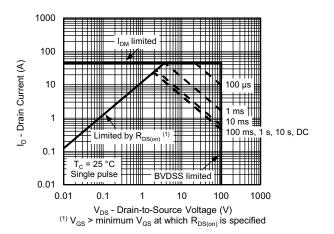
Drain Source Breakdown vs. Junction Temperature

4

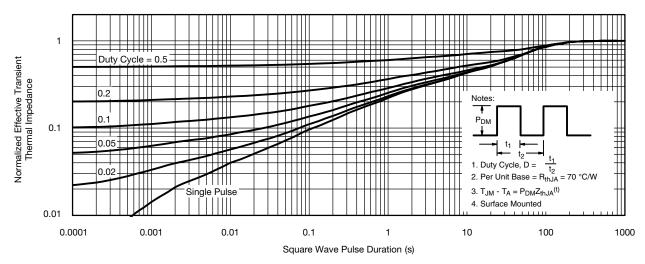
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### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



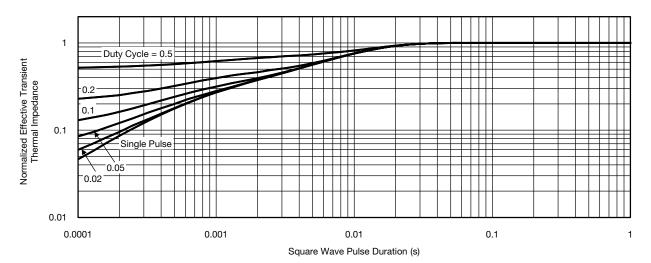
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

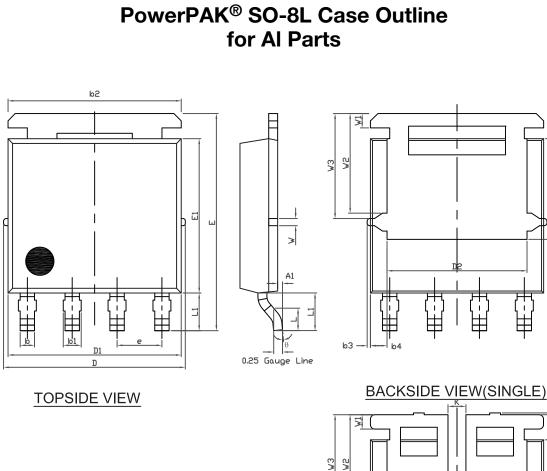
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

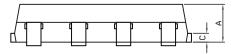
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

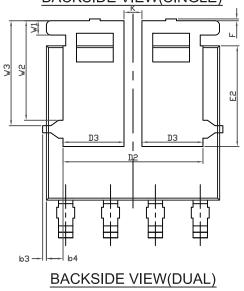
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## **Package Information**



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DIM		MILLIMETERS		INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К		0.51			0.020		
W		0.23			0.009		
W1	0.41			0.016			
W2		2.82			0.111		
W3		2.96			0.117		
q	0°	-	10°	0°	-	10°	

Note

• Millimeters will gover



### RECOMMENDED MINIMUM PAD FOR PowerPAK<sup>®</sup> SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)

Revision: 07-Feb-12

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